

# isc P-Channel MOSFET Transistor

## AOI423

### FEATURES

- Drain Current –I\_D= -70A@ T\_C=25 $^\circ\!\!\mathbb{C}$
- Drain Source Voltage-: V<sub>DSS</sub>= -30V(Min)
- Static Drain-Source On-Resistance
- :  $R_{DS(on)}$  = 8.5m  $\Omega$  (Max)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

#### DESCRIPTION

• Designed for use in switch mode power supplies and general purpose applications.

ADSOLUTE MAAIMUW RATINGS(Ta=25 C)						
SYMBOL	PARAMETER VAL		UNIT			
V <sub>DSS</sub>	Drain-Source Voltage -30		V			
V <sub>GS</sub>	Gate-Source Voltage-Continuous	±25	V			
ID	Drain Current-Continuous	-70	A			
I <sub>DM</sub>	Drain Current-Single Pluse	-200	A			
PD	Total Dissipation @T <sub>c</sub> =25℃	90	W			
TJ	Max. Operating Junction Temperature	-55~175	°C			
T <sub>stg</sub>	Storage Temperature	-55~175	°C			

### ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

## DD pin 1.Gate 2.Drain 3. Source DPAK TO-252 package C 0.5 K C ÷ D 3 0 G H H mm MIN MAX DIM 6.40 6.60 A 5.20 5.40 В C 1.15 1. 35 D 5.70 6.10 0.65 F G 0.75 Н 2.10 2.50 2.10 2.40

0.40 0.60 0.90 1.10 9.90 10.1

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	1.6	°C/W

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### **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
V(BR)DSS	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = -0.25mA	-30		V
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{DS}$ = $V_{GS}$ ; $I_{D}$ = -0.25mA	-0.7	-1.4	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = -10V; I <sub>D</sub> = -20A		8.5	mΩ
lgss	Gate-Body Leakage Current	V <sub>GS</sub> = ±25V;V <sub>DS</sub> = 0		±100	nA
loss	Zero Gate Voltage Drain Current	V <sub>DS</sub> = -30V; V <sub>GS</sub> = 0 V <sub>DS</sub> = -30V; V <sub>GS</sub> = 0@T <sub>J</sub> =55°C		-1 -5	μA
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> = -1A; V <sub>GS</sub> = 0		-1	V



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